



ZXTP19040CGQ

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BV_{CEO} > -40V
- I_C = -3A High Continuous Collector Current
- I_{CM} = -5A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(SAT)} < -200mV @ -1.0A
- Lead-Free Finish & RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

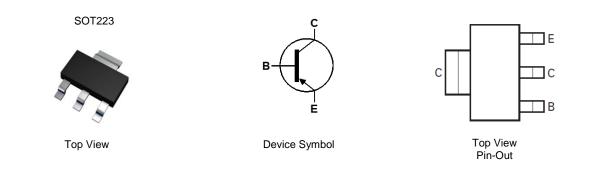
-40V PNP LOW VCESAT TRANSISTOR IN SOT223

Applications

- DC to DC Conversion
- Supply Line Switching
- Low Dropout Regulation
- LCD Backlighting

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP19040CGQ-7	Automotive	TP19040C	7	12	1,000

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

 See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

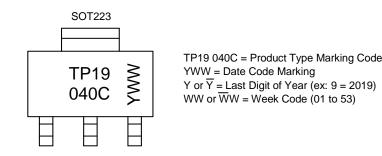
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





ZXTP19040CGQ

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	lc	-3	A
Peak Pulse Collector Current	I _{CM}	-5	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	1.2	W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	104	°C /W
Power Dissipation	(Note 7)	PD	2	W
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	62.5	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

ESD Ratings (Note 8)

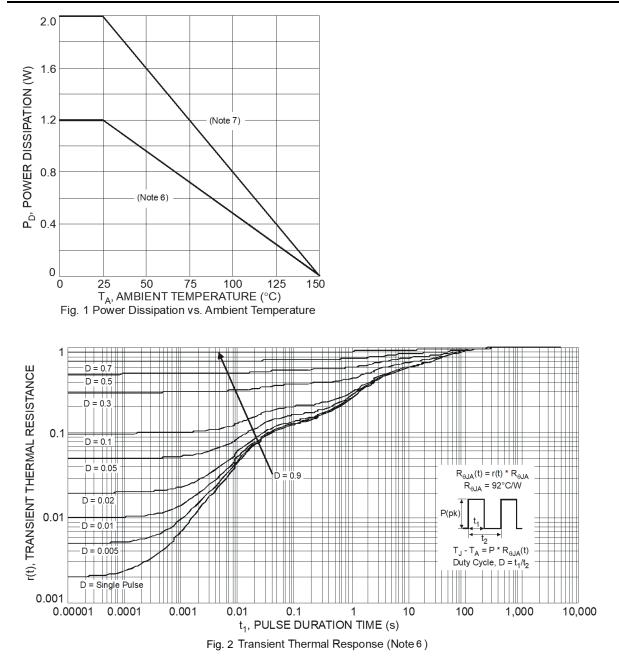
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

Device mounted on FR-4 PCB with minimum recommended pad layout.
 Device mounted on FR-4 PCB using 2oz copper and 25mm x 25mm pad layout.
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





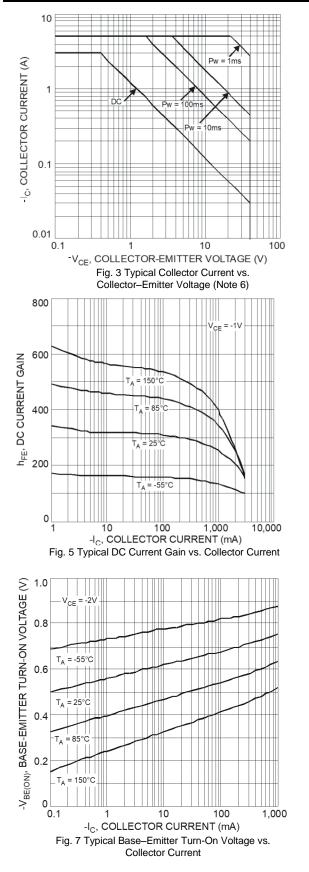
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

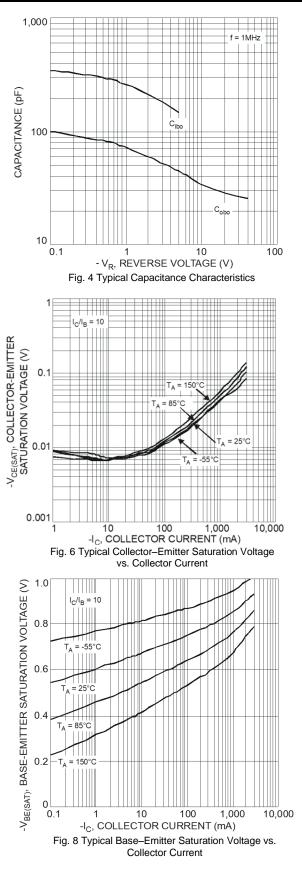
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Conditions	
OFF CHARACTERISTICS (Note 9)	0,		• 76		•		
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_		V	$I_{\rm C} = -100 \mu {\rm A}$	
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40	_	_	V	$I_{\rm C} = -10 {\rm mA}$	
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	—	—	V	I _E = -50μA	
Collector-Base Cutoff Current			—	-100	nA	$V_{CB} = -40V, I_E = 0$	
Collector-Base Cuton Current	I _{СВО}	_	_	-50	μA	$V_{CB} = -40V, I_E = 0, T_A = +150^{\circ}C$	
Emitter-Base Cutoff Current	I _{EBO}	_	—	-100	nA	$V_{EB} = -6V, I_{C} = 0$	
ON CHARACTERISTICS (Note 9)						·	
		220	_			$V_{CE} = -1V, I_{C} = -0.5A$	
DC Current Gain	h _{FE}	200	_	400		$V_{CE} = -1V, I_{C} = -1A$	
		100	_			$V_{CE} = -1V, I_{C} = -3A$	
		_	_	-150		$I_{C} = -0.5A, I_{B} = -5mA$	
Collector-Emitter Saturation Voltage	V _{CE(SAT)}		_	-200	mV	$I_{\rm C} = -1A, I_{\rm B} = -10mA$	
		_	_	-500		$I_{C} = -3A, I_{B} = -0.3A$	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	—	-1.0	V	$I_{\rm C} = -1$ A, $I_{\rm B} = -0.1$ A	
Base-Emitter Turn-On Voltage	V _{BE(ON)}	_	_	-1.0	V	$V_{CE} = -2V, I_{C} = -1A$	
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency	f⊤		150	—	MHz	$V_{CE} = -10V, I_C = -100mA, f = 100MHz$	
Output Capacitance	C _{obo}	_	35	_	pF	$V_{CB} = -10V, f = 1MHz$	
Input Capacitance	C _{ibo}	_	150	_	pF	$V_{CB} = -5V, f = 1MHz$	
SWITCHING CHARACTERISTICS							
Turn-On Time	t _{ON}	_	53	_	ns	101/1 20	
Delay Time	t _D	—	12		ns	V _{CC} = -10V, I _C = -2A, I _{B1} = -200mA	
Rise Time	t _R	_	41	_	ns	1B120011A	
Turn-Off Time	toff	_	180		ns	101/1 00	
Storage Time	ts	_	146	_	ns	V _{CC} = -10V, I _C = -2A, I _{B1} = -I _{B2} = -200mA	
Fall Time	t _F		34		ns	$_{1B1} ={1B2} ={20011}$	

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



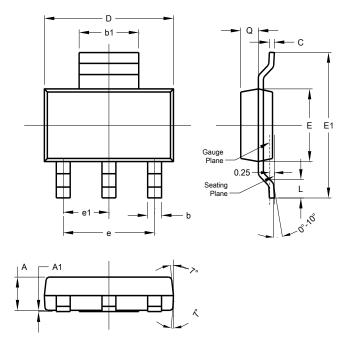




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

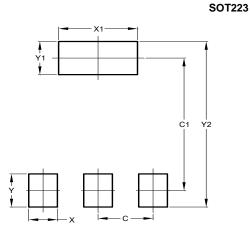
SOT223



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
E	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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